## **ELECTRICAL CHARACTERISTICS**

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PARAMETER	NP0		X7R		X5R	
TEMPERATURE COEFFICIENT:	0± 30 ppm/°C	-55 to +125°C	± 15%	-55 to +125°C	± 15%	-55 to +85°C
OCCITION.	275 275 275 275 275 275 277 277 277 277	are are tare tare	25 25 25 25 25 25 25 25 25 25 25 25 25 2	E BITC NYC 1BITC 121/C	20 00 00 00 00 00 00 00 00 00 00 00 00 0	c are are tare
DISSIPATION FACTOR:	.001 (0.1%) max		WVDC ≥ 50 VDC, DF = 2.5% max WVDC = 25 VDC, DF = 3.0% max WVDC = 16 VDC, DF = 3.5% max		For Vrated ≥ 50 VDC, DF = 5% max For Vrated ≤ 25 VDC: DF = 10% max	
AGING:	None		2.5% / decade hour		2.5 % / decade hour	
INSULATION RESISTANCE:	1000ΩF or 100GΩ whichever is less @ 25°C, WVDC		500ΩF or 50GΩ whichever is less @ 25°C, WVDC		100ΩF or 10GΩ whichever is less @ 25°C, WVDC	
DIELECTRIC STRENGTH:	For Vrated = 6 - 200 VDC, DWV = 2.5 X WVDC, 25°C, 50mA max. For Vrated = 201 - 499 VDC, DWV = 2.0 X WVDC, 25°C, 50mA max. For Vrated = 500 - 999 VDC, DWV = 1.5 X WVDC, 25°C, 50mA max. For Vrated = 1000+ VDC, DWV = 1.2 X WVDC, 25°C, 50mA max.					
TEST PARAMETERS:	C > 100 pF; 1kHz ±50Hz;1.0±0.2 VRMS C ≤ 100 pF 1Mhz ±50kHz; 1.0±0.2 VRMS		Capacitance values ≤ 10 µF: 1.0kHz±50Hz @ 1.0±0.2 Vrms Capacitance values > 10 µF: 120Hz±10Hz @ 0.5V±0.1 Vrms		Capacitance values ≤ 10 μF: 1.0kHz±50Hz @ 1.0±0.2 Vrms Capacitance values > 10 μF: 120Hz±10Hz @ 0.5V±0.1 Vrms	
NOTES:		ΩF or 10 GΩ ated ≥ 50 VDC = 5° ated ≤ 25 VDC, DF				